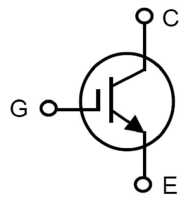
IXYS

XPT™ 650V GenX5™ IGBT

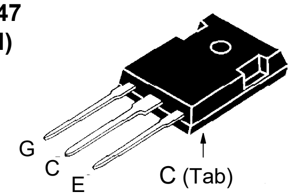
IXYH90N65A5

V_{CES} = 650V
I_{C110} = 90A
$V_{CE(sat)}$ ≤ 1.35V
$t_{fi(typ)}$ = 220ns

Extreme Light Punch Through
IGBT for up to 10kHz Switching



TO-247
(IXYH)



G = Gate C = Collector
E = Emitter Tab = Collector

Symbol	Test Conditions	Maximum Ratings	
V_{CES}	T_J = 25°C to 175°C	650	V
V_{CGR}	T_J = 25°C to 175°C, R_{GE} = 1MΩ	650	V
V_{GES}	Continuous	±20	V
V_{GEM}	Transient	±30	V
I_{C25}	T_C = 25°C (Chip Capability)	220	A
I_{LRMS}	Terminal Current Limit	160	A
I_{C110}	T_C = 110°C	90	A
I_{CM}	T_C = 25°C, 1ms	600	A
SSOA (RBSOA)	V_{GE} = 15V, T_{VJ} = 150°C, R_G = 5Ω Clamped Inductive Load	I_{CM} = 180 $V_{CE} \leq V_{CES}$	A
P_C	T_C = 25°C	650	W
T_J		-55 ... +175	°C
T_{JM}		175	°C
T_{stg}		-55 ... +175	°C
T_L	Maximum Lead Temperature for Soldering 1.6 mm (0.062 in.) from Case for 10s	300	°C
M_d	Mounting Torque	1.13 / 10	Nm/lb.in
Weight		6	g

Symbol	Test Conditions (T_J = 25°C, Unless Otherwise Specified)	Characteristic Values Min.	Typ.	Max.	
BV_{CES}	I_C = 250μA, V_{GE} = 0V	650			V
$V_{GE(th)}$	I_C = 250μA, V_{CE} = V_{GE}	3.7		5.8	V
I_{CES}	V_{CE} = V_{CES}, V_{GE} = 0V			5	μA
	T_J = 150°C			500	μA
I_{GES}	V_{CE} = 0V, V_{GE} = ±20V			±100	nA
$V_{CE(sat)}$	I_C = 60A, V_{GE} = 15V, Note 1		1.22	1.35	V
	T_J = 150°C		1.30		V

Features

- Optimized for Low Frequency High Current Switching
- High Surge Current Capability
- Square RBSOA
- International Standard Package

Advantages

- High Power Density
- Low Gate Drive Requirement

Applications

- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts

Symbol	Test Conditions (T_J = 25°C Unless Otherwise Specified)	Characteristic Values Min.	Typ.	Max.
g_{fs}	I_C = 60A, V_{CE} = 10V, Note 1	40	68	S
C_{ies}	V_{CE} = 25V, V_{GE} = 0V, f = 1MHz		4040	pF
C_{oes}			200	pF
C_{res}			150	pF
$Q_{g(on)}$	I_C = 90A, V_{GE} = 15V, V_{CE} = 0.5 • V_{CES}		260	nC
Q_{ge}			33	nC
Q_{gc}			128	nC
$t_{d(on)}$	**Inductive load, T_J = 25°C**		40	ns
t_{ri}	I_C = 50A, V_{GE} = 15V		46	ns
E_{on}	V_{CE} = 400V, R_G = 5Ω		1.3	mJ
$t_{d(off)}$	Note 2		420	ns
t_{fi}			220	ns
E_{off}			3.4	mJ
$t_{d(on)}$	**Inductive load, T_J = 150°C**		24	ns
t_{ri}	I_C = 50A, V_{GE} = 15V		44	ns
E_{on}	V_{CE} = 400V, R_G = 5Ω		2.8	mJ
$t_{d(off)}$	Note 2		380	ns
t_{fi}			360	ns
E_{off}			5.0	mJ
R_{thJC}				0.23 °C/W
R_{thCS}			0.21	°C/W

Notes:
1. Pulse test, t ≤ 300μs, duty cycle, d ≤ 2%.
2. Switching times & energy losses may increase for higher V_{CE}(clamp), T_J or R_G.

Fig. 1. Output Characteristics @ T_J = 25ºC

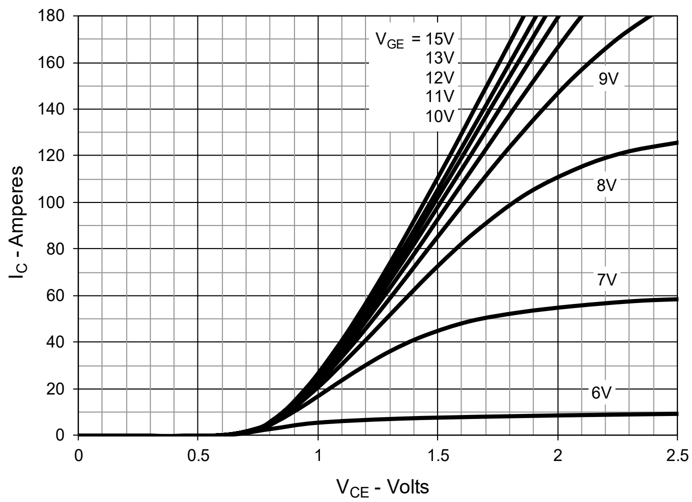


Fig. 2. Extended Output Characteristics @ T_J = 25ºC

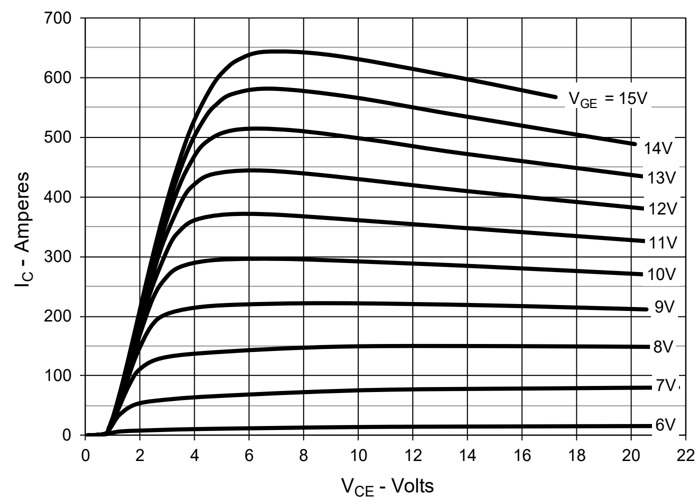


Fig. 3. Output Characteristics @ T_J = 150ºC

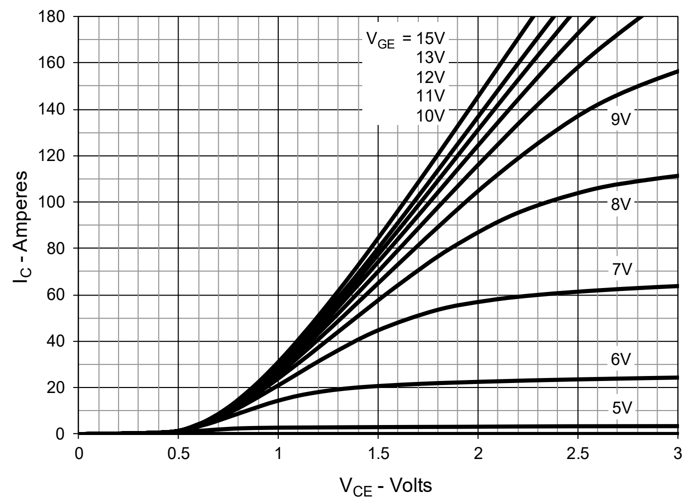


Fig. 4. Dependence of $V_{CE(sat)}$ on Junction Temperature

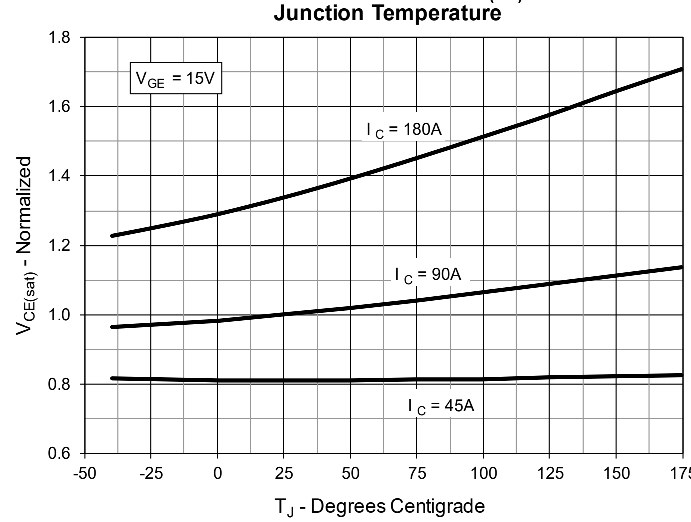


Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage

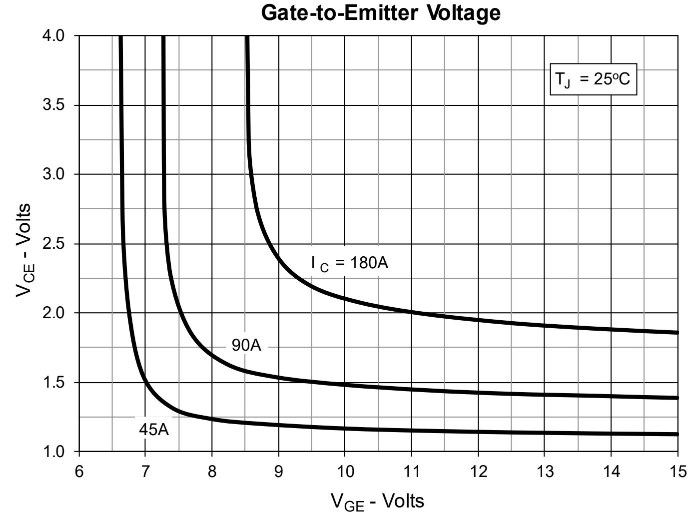


Fig. 6. Input Admittance

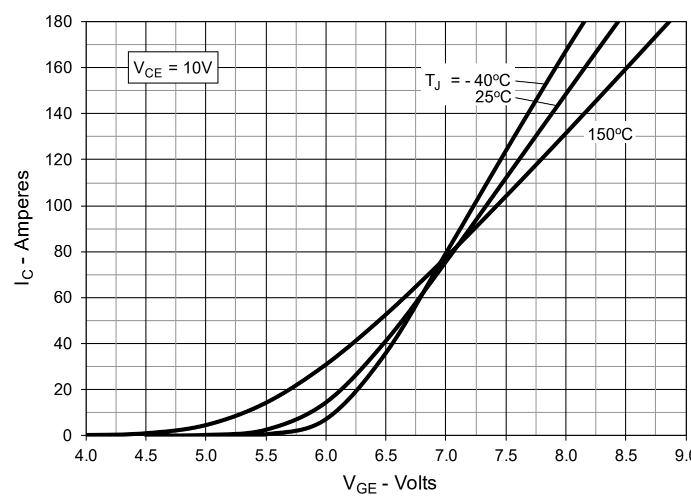


Fig. 7. Transconductance

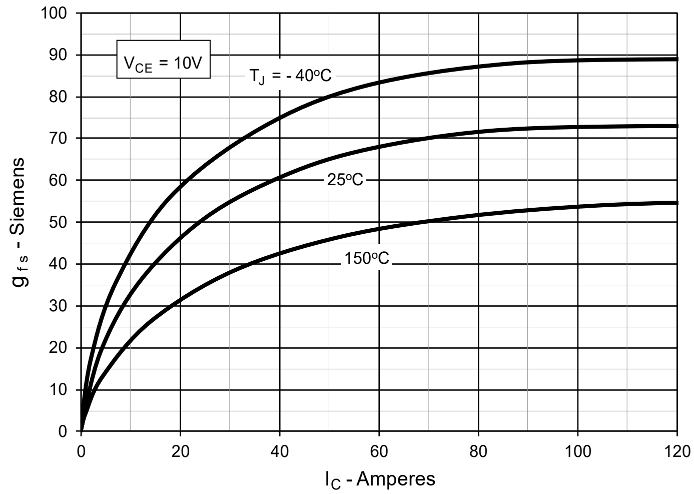


Fig. 8. Gate Charge

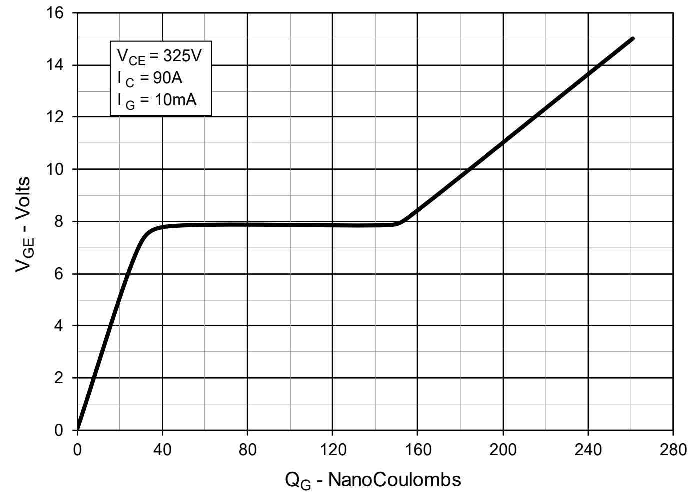


Fig. 9. Capacitance

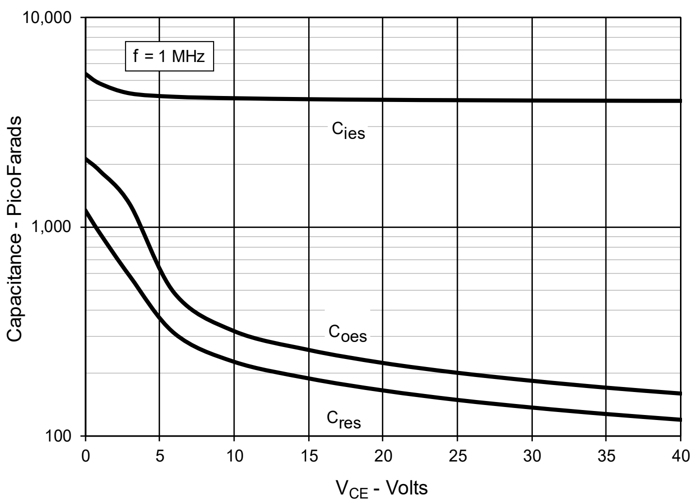


Fig. 10. Reverse-Bias Safe Operating Area

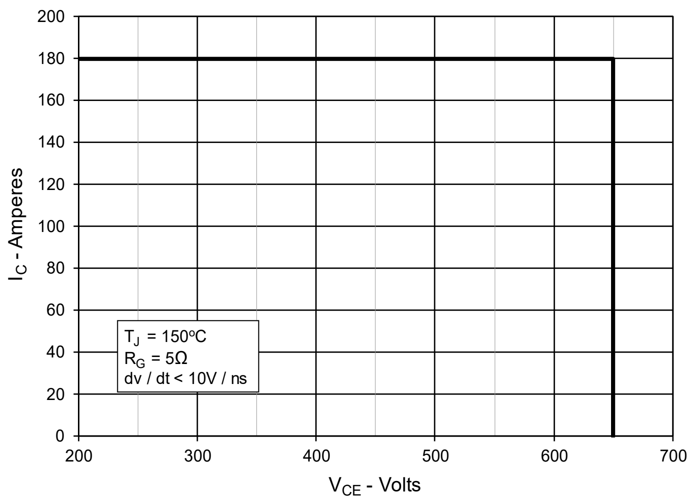


Fig. 11. Maximum Transient Thermal Impedance

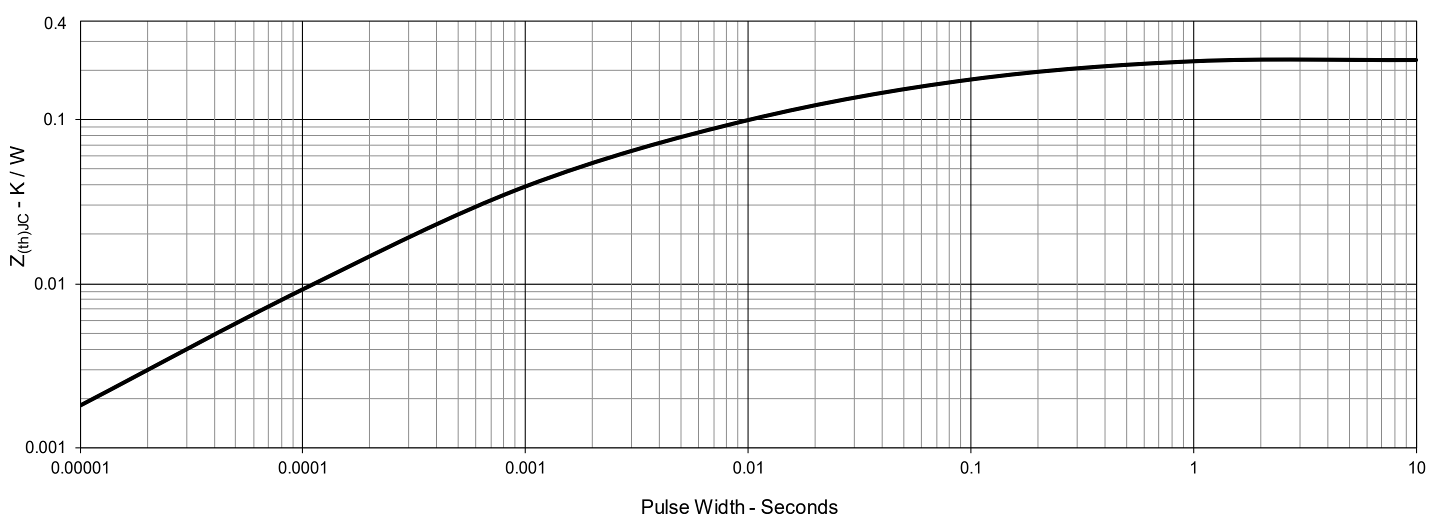


Fig. 12. Inductive Switching Energy Loss vs. Collector Current

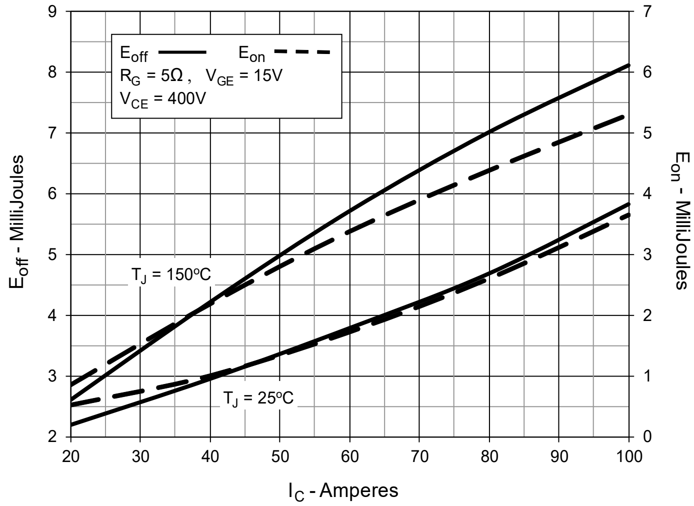


Fig. 13. Inductive Switching Energy Loss vs. Gate Resistance

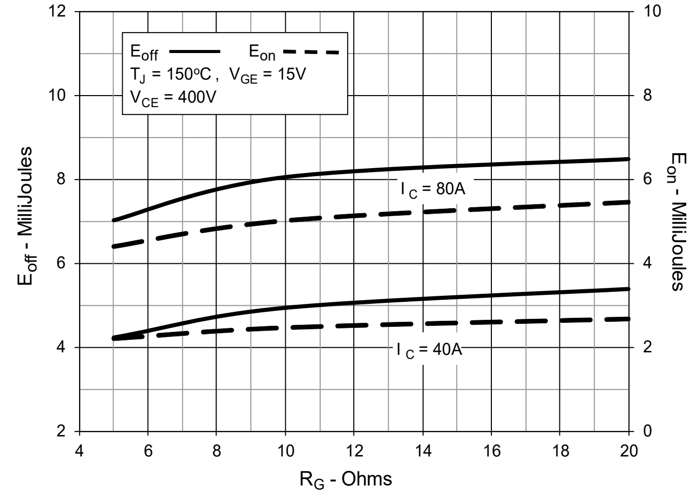


Fig. 14. Inductive Switching Energy Loss vs. Junction Temperature

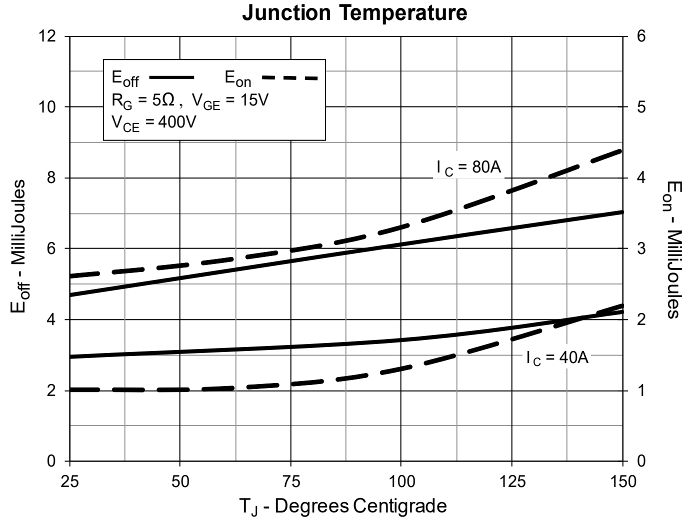


Fig. 15. Inductive Turn-off Switching Times vs. Gate Resistance

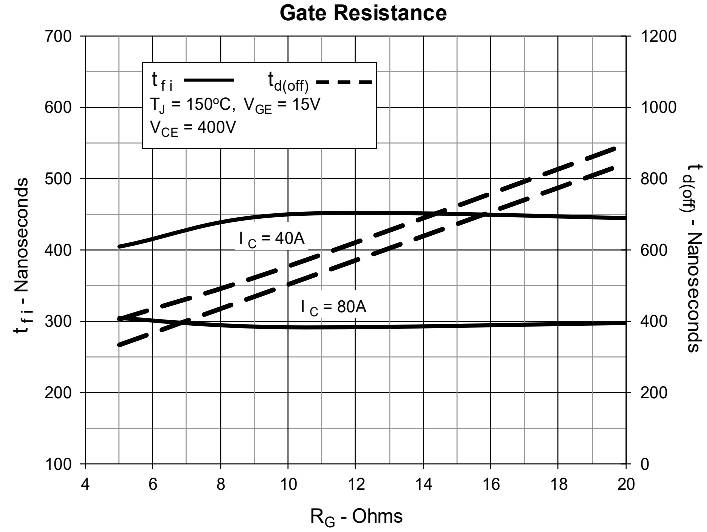


Fig. 16. Inductive Turn-off Switching Times vs. Collector Current

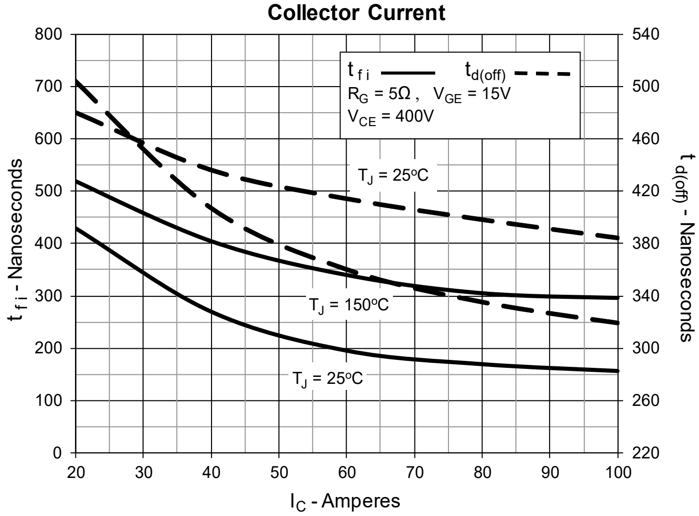


Fig. 17. Inductive Turn-off Switching Times vs. Junction Temperature

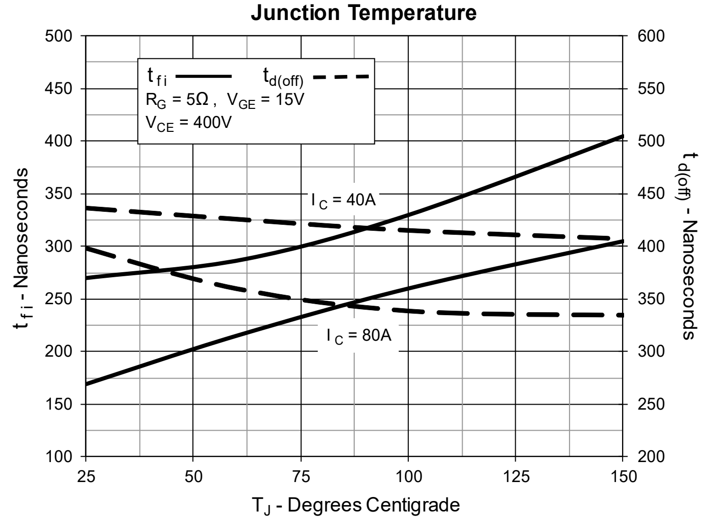


Fig. 18. Inductive Turn-on Switching Times vs. Gate Resistance

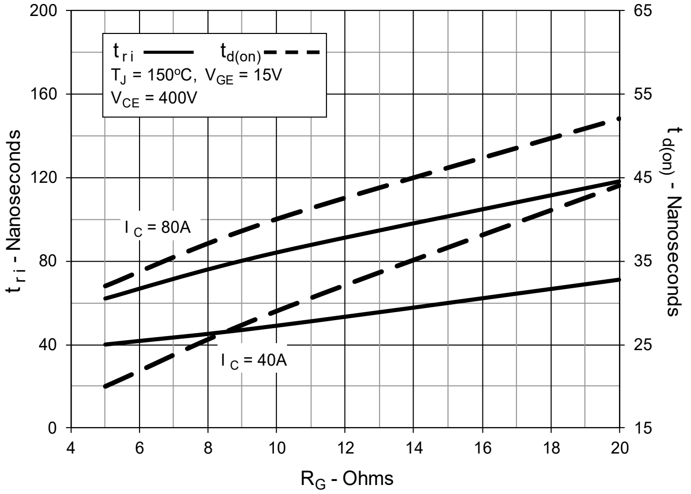


Fig. 19. Inductive Turn-on Switching Times vs. Collector Current

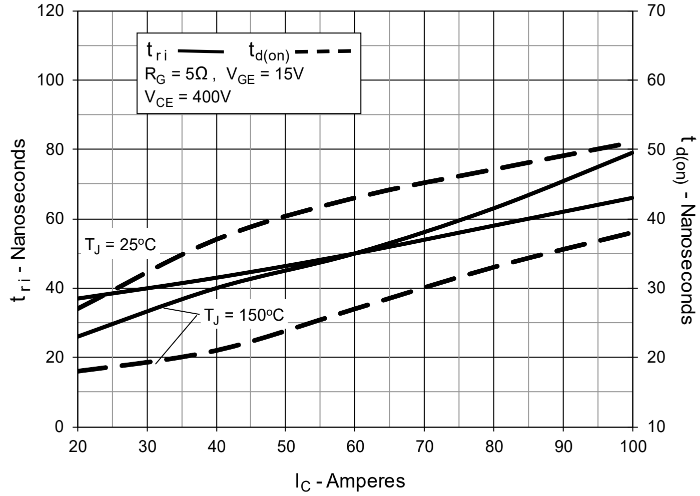


Fig. 20. Inductive Turn-on Switching Times vs. Junction Temperature

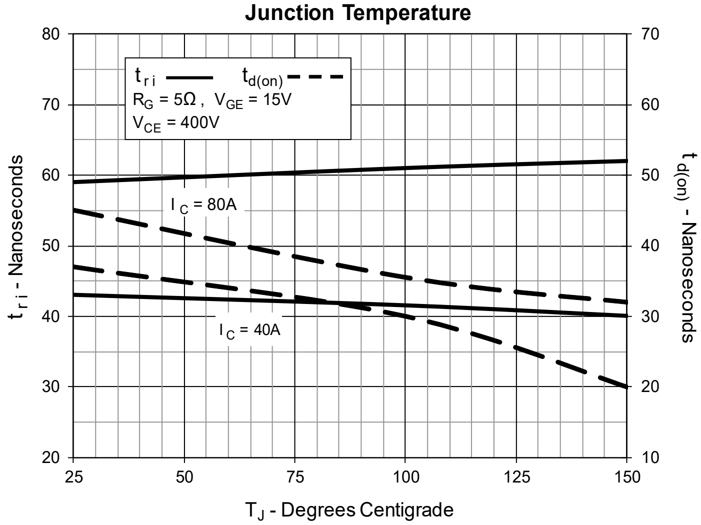
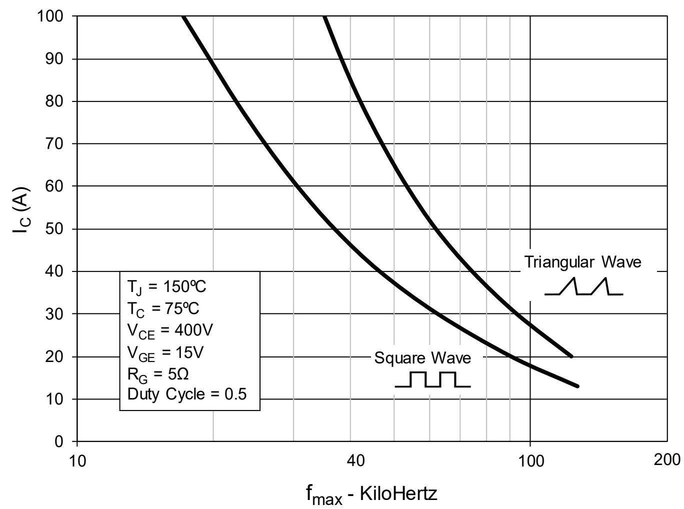
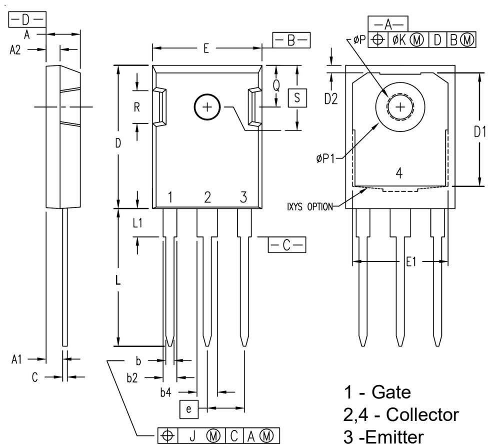


Fig. 21. Maximum Peak Load Current vs. Frequency



TO-247 Outline



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
C	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
E	.620	.635	15.75	16.13
E1	.545	.565	13.84	14.35
e	.215 BSC		5.45 BSC	
J	--	.010	--	0.25
K	--	.025	--	0.64
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
øP	.140	.144	3.55	3.65
øP1	.275	.290	6.99	7.37
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.242 BSC		6.15 BSC	